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# Hierarchical MoS<sub>2</sub> microspheres prepared through a zinc ion-assisted hydrothermal route as an electrochemical supercapacitor electrode†

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Hierarchical molybdenum disulfide microspheres have been successfully prepared through a zinc ion-assisted hydrothermal route followed by an acid corrosion strategy. It is found that the MoS<sub>2</sub> microspheres comprised of numerous nanosheets with few-layered feature exhibit a 3D flower-like morphology. It is believed that the MoS<sub>2</sub>/ZnS composites can act as a precursor for the formation of hierarchical MoS<sub>2</sub> microspheres. Additionally, the electrochemical properties of the as-prepared MoS<sub>2</sub> microspheres as an electrode material for supercapacitors have also been investigated. Compared with the MoS<sub>2</sub> nanosheet, the resultant MoS<sub>2</sub> microsphere demonstrates superior pseudocapacitive properties including high specific capacitance, good cycling and rate capability, which could be credited to its novel hierarchical architecture feature.

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## 1. Introduction

The ever-increasing applications of portable electronic devices and electric vehicles have evoked intensive research interest for developing high-performance energy storage devices.<sup>1</sup> As a category of important energy storage devices, supercapacitors have received great attention for their many attractive merits such as excellent cycling stability, high specific capacitance and power density, good charging-discharging rates and safety.<sup>2</sup> According to the charge storage mechanism, supercapacitors can be divided into electric double-layer capacitors (EDLC) and pseudocapacitors (PC). Amongst them, pseudocapacitors can store charge by redox-based faradaic reactions, and thus can have higher capacitance values than EDLCs.<sup>3</sup> At present, one of key research themes of PCs is exploring new-type and high-performance electrode materials in order to achieve high capacity, long cycle life, high power/energy density and low cost.<sup>4</sup> A series of transition metal oxides such as RuO<sub>2</sub>, CoO<sub>x</sub>, NiO, MnO<sub>2</sub>, and so forth, have been widely investigated as classic examples for pseudocapacitors.<sup>5–8</sup>

The discovery of graphene and its unusual properties have aroused interest in other layered materials.<sup>9</sup> Specially, layered

transition-metal dichalcogenides which are characteristic of relatively weak interactions between the layers and the strong intralayer covalent bonding interactions have gained more and more attention due to their uncommon electronic, chemical and physical properties as well as potential applications in catalysis, sensors and energy generation and storage.<sup>10–14</sup> Thereinto, MoS<sub>2</sub> is a typical example existing in different forms such as 2H semiconductor phase (2H-MoS<sub>2</sub>) and 1T metallic phase (1T-MoS<sub>2</sub>) and has been reported to possess pseudocapacitive charge-storage property.<sup>15–17</sup> MoS<sub>2</sub> can store charge based on the ions intercalation into the layers of MoS<sub>2</sub> accompanied by a faradaic charge-transfer. This mechanism can be termed as intercalation pseudocapacitance.<sup>18,19</sup> Until now, a variety of MoS<sub>2</sub>-based nanomaterials have been synthesized for supercapacitor applications.<sup>20</sup> For example, Huang hydrothermally synthesized 2H-MoS<sub>2</sub> nanosheets that demonstrated a specific capacitance of 129 F g<sup>-1</sup> at 1 A g<sup>-1</sup>.<sup>21</sup> However, inferior conductivity of 2H-MoS<sub>2</sub> would impair its electrochemical performance. To circumvent this issue, fabricating MoS<sub>2</sub> with metallic features and compositing MoS<sub>2</sub> with other conductive materials have been confirmed as effective ways. For instance, Chhowalla found that chemically exfoliated MoS<sub>2</sub> nanosheets contained a high concentration of the metallic 1T phase and can electrochemically intercalate H<sup>+</sup> and alkali metal ions with extraordinary efficiency.<sup>22</sup> Zhu *et al.* first employed hydrothermal techniques to synthesize water-coupled metallic MoS<sub>2</sub> nanosheets which exhibited excellent capacitive performances.<sup>23</sup> 2H-MoS<sub>2</sub>/carbon nanotube and MoS<sub>2</sub>/carbon aerogel hybrids were also prepared and delivered a high capacitance of 452 and 260 F g<sup>-1</sup> at 1 A g<sup>-1</sup>, respectively.<sup>24,25</sup> Additionally, the reduction of active surfaces originating from the overlapping or

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restacking of MoS<sub>2</sub> nanosheets as well as structural instability during repeated ions insertion/extraction can also lead to an unsatisfied electrochemical performances.<sup>26–28</sup> Fabricating hierarchical MoS<sub>2</sub> nanostructures is considered to be an efficient pathway to solve this problem.<sup>29,30</sup> Hierarchical nanostructures, which are assembled from 0D, 1D and 2D nanomaterials as building blocks have attracted significant attention based on the fact that the hierarchical structures could supply efficient channels for transport of both electrons and ions, exhibit high surface area, shorten ion diffusion length, strengthen the structural stability and thus improve their electrochemical performance.<sup>31–33</sup> Various MoS<sub>2</sub> hierarchical nanostructures such as binder-free nanoarrays, nano-sponges and nanoflowers have been reported to manifest superior electrochemical performances.<sup>34–36</sup>

In a liquid-phase synthetic route towards hierarchical MoS<sub>2</sub> nanostructures, some organics including surfactants, polymers, complexing agents, ionic liquids and amines were usually employed as a structure-directing agent which might produce pollutants leading to environmental damage.<sup>37–40</sup> Herein, we present a facile zinc ion-assisted hydrothermal method to prepare hierarchical MoS<sub>2</sub> microspheres assembled by 2D nanosheets, which exhibit superior electrochemical performance as an electrode for pseudocapacitor.

## 2. Experimental section

### 2.1 Zinc ion-assisted hydrothermal synthesis of hierarchical MoS<sub>2</sub> microspheres

In a typical synthesis, 1.5 mmol of zinc nitrate hexahydrate was dissolved in 30 mL deionized water to form a clear solution. Then 30 mL of 0.05 M sodium molybdate solution was slowly dropped into the above solution under vigorous stirring. No obvious precipitates can be observed. After that, 9 mmol of thiocarbamide was also dissolved into the above solution. Finally, the resulting solution was transferred into a 100 mL of Teflon-lined stainless steel autoclave and maintained at 240 °C for 24 h. Finally, the hydrothermal products were collected and redispersed into 0.5 M HCl solution to remove possible zinc sulfide residues. Then the products were washed with water and alcohol and dried at 60 °C for 6 h in a vacuum oven. The hydrothermal product was then annealed in a tube furnace at 500 °C for 2 h under nitrogen atmosphere to improve the crystallinity. For comparison, the MoS<sub>2</sub> nanosheets as well as ZnS products were also prepared by a similar method.

### 2.2 Characterizations

X-ray diffraction patterns (XRD) were obtained with a D/Max-2550 X-ray diffractometer using monochromatized CuK $\alpha$  radiation. TEM and HRTEM characterizations were carried out on a JEOL JFL-2010 TEM operating at 200 kV, for which the samples were prepared by dispersing them in acetone and drop-casting onto a 200 mesh copper grid coated with holey carbon. SEM observations were conducted by using a SIRION-100 field emission scanning electron microscopy (SEM). The elemental composition was analyzed by energy dispersive X-ray

spectroscopy (EDX, GENESIS-4000). X-ray photoelectron spectra (XPS) were processed on a Perkin-Elmer PHI5000c XPS, using C 1s (B. E. 284.6 eV) as a reference. Raman spectra were recorded using excitation with a 514 nm argon ion laser at 6 mW for 50 s on a Jobin Yvon LabRam HR spectrometer. The nitrogen sorption analysis was conducted at 77 K on a Quantachrome NOVA 2000e sorption analyzer and the Brunauer–Emmett–Teller (BET) surface area was estimated from the adsorption data. Electrochemical impedance spectroscopy (EIS) was obtained by applying a voltage amplitude of 5 mV in the frequency range from 100 kHz to 0.01 Hz on a CHI660E.

### 2.3 Electrochemical measurements

Electrochemical performance of the supercapacitor was studied by cyclic voltammetry (CV) and galvanostatic charge/discharge (GCD) at an electrochemical station (CHI660E). The electrochemical tests were performed in 3 M KOH electrolyte using a three electrode cell composed of a saturated calomel electrode (SCE) as reference, Pt plate as counter and the samples-based electrode as the working electrode. Working electrodes were fabricated by mixing electroactive material, carbon black and poly(vinylidene fluoride) in a mass ratio of 80 : 10 : 10 to obtain a slurry. Then the slurry was pressed onto the nickle foam current collector (1 cm<sup>2</sup>) and dried at 60 °C for 12 h. The electroactive mass loading on the nickle foam is calculated to be 3.57 mg. The scan rate of the CV response varied from 5 to 100 mV s<sup>-1</sup> with the potential range from -0.2 to 0.45 V. The capacitance values at various scan rate were calculated according to the CV curves as following eqn (1):

$$C = \int idV / 2v\Delta V \quad (1)$$

The specific capacitances at different current density were calculated from the GCD curves according to eqn (2):

$$C = I\Delta t / \Delta V m \quad (2)$$

where  $C$  is the specific capacitance,  $\int idV$  is the integrated area of the CV curves,  $v$  is the scan rate,  $\Delta V$  is the potential window,  $I$  is the discharge current,  $\Delta t$  is the discharge time,  $m$  is the mass of the electroactive material loading on nickle foam.

## 3. Results and discussions

### 3.1 Microstructure and morphology of the samples

Fig. 1 shows the XRD patterns of the as-prepared MoS<sub>2</sub> nanosheets and MoS<sub>2</sub> microspheres. It is clearly seen that all the MoS<sub>2</sub> samples agree well with a hexagonal structure of MoS<sub>2</sub> (JCPDS 37-1492), in which the diffraction peaks at  $2\theta = 14.2^\circ$ ,  $33.4^\circ$ ,  $39.8^\circ$ ,  $49.4^\circ$ ,  $59.1^\circ$  and  $69.8^\circ$  can be unambiguously assigned to the (002), (100), (103), (105), (110) and (203) planes, respectively. No obvious peaks from the impurity ZnS phase can be observed in the XRD patterns of Fig. 1b, which confirms that residual zinc sulfide in hydrothermal products has been completely removed by the following acid treatment. The (002)



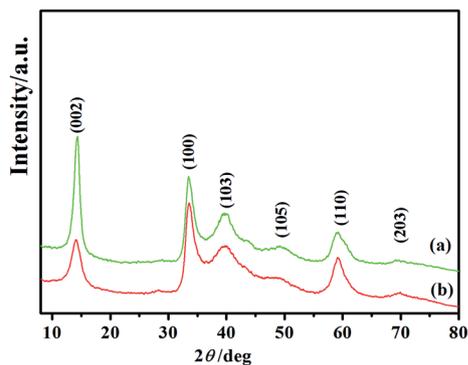


Fig. 1 XRD patterns of (a) the as-prepared MoS<sub>2</sub> nanosheets and (b) MoS<sub>2</sub> microspheres.

reflection of layered MoS<sub>2</sub> at  $2\theta = 14.2^\circ$  can be indicative of an interlayer spacing of 0.62 nm according to Bragg's equation, which is in agreement with that of 2H phase MoS<sub>2</sub>. In comparison with Fig. 1a, the prominently weakened (002) peak in Fig. 1b indicates that the crystal growth of MoS<sub>2</sub> layers were inhibited to a certain extent which might be due to the physical confinement of the ZnS produced in hydrothermal process. The stacking layers of MoS<sub>2</sub> microspheres could be estimated to be approximately  $\sim 5$  layers in the light of FWHM of (002) reflection using Scherrer's equation, visibly less than those of the MoS<sub>2</sub> nanosheets ( $\sim 11$  layers).

Fig. 2a provides the morphology of the as-prepared MoS<sub>2</sub> nanosheets, which are scattered nanosheets. In sharp contrast to the MoS<sub>2</sub> nanosheets, Fig. 2b indicates that the MoS<sub>2</sub> products are hierarchical microspheres with sizes of  $\sim 1.5 \mu\text{m}$ . Moreover, it can be discerned that these MoS<sub>2</sub> microspheres are comprised of folded sheet-like subunits. The neighboring nanosheets on surface are interconnected and obvious open spaces exist between them. With a closer examination with TEM (Fig. 2c), these curled nanosheets stretch out towards the edges of the spheres and aggregate to form relatively loose microspheres. Fig. 2d clearly reveals the few-layered characteristic of the nanosheets in MoS<sub>2</sub> microspheres. These dispersed nanosheets display a 4–6 layer thickness with a lattice spacing of 0.62 nm between two adjacent layers, which is in line with XRD results. The de-layered structures can be favourable to decreasing the interlayer resistance and accelerating electron transfer between MoS<sub>2</sub> layers. The elemental composition of the MoS<sub>2</sub> microspheres were identified by EDX as shown in Fig. 2e. It can be seen that the MoS<sub>2</sub> spheres contain C, O, Mo and S elements. The little amount of C and O elements could come from the air adsorption. The atomic ratio of S to Mo is calculated as 2.07, which agrees with the MoS<sub>2</sub> stoichiometry.

The chemical states and compositions of the MoS<sub>2</sub> microspheres were studied by XPS. As shown in Fig. 3a, the Mo 3d orbit demonstrates two peaks located at 229.0 and 232.4 eV, which can be ascribed to the doublet of Mo(IV) 3d<sub>5/2</sub> and Mo 3d<sub>3/2}, respectively.<sup>41,42</sup> Besides, a small shoulder signal arising from 236.04 eV can be characteristic of a +6 oxidation state.<sup>41,42</sup> Fig. 3b reveals that the S 2p core-level XPS spectrum can be divided into two peaks, indicating existence of two chemical</sub>

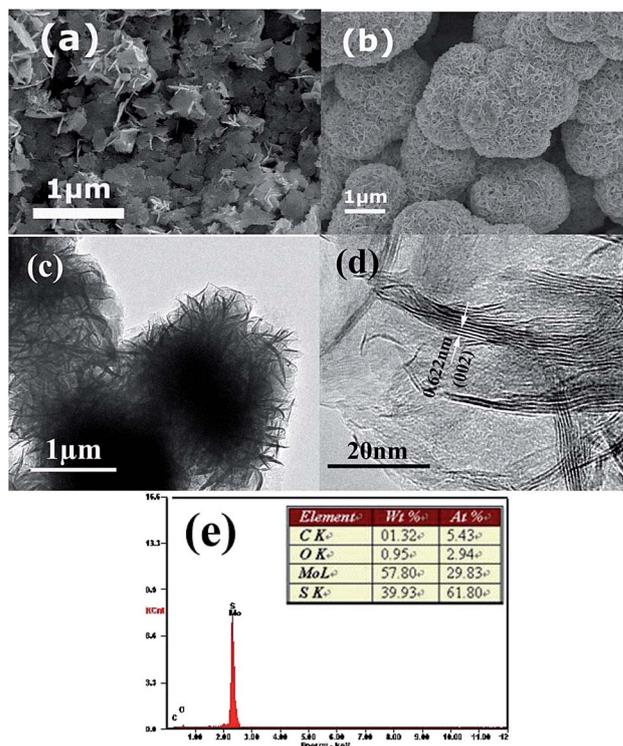


Fig. 2 SEM images of (a) MoS<sub>2</sub> nanosheets and (b) MoS<sub>2</sub> microspheres; (c) TEM image, (d) HRTEM image and (e) EDX pattern of MoS<sub>2</sub> microspheres.

environments. The peaks at 161.95 and 163.09 eV can be attributed to the binding energies of S 2p<sub>3/2} and S 2p<sub>1/2}.<sup>41,42</sup> The estimated atomic ratio of S : Mo is about 2.12, agreeing with the result of EDX.</sub></sub>

Fig. 4 provides the Raman spectra of the as-prepared MoS<sub>2</sub> samples. The MoS<sub>2</sub> microspheres demonstrate two characteristic peaks situated at 378.25 cm<sup>-1</sup> (E<sub>2g</sub><sup>1</sup> mode) and 402.24 cm<sup>-1</sup> (A<sub>1g</sub> mode). For the MoS<sub>2</sub> nanosheets, the peaks at 378.25 and 403.53 cm<sup>-1</sup> correspond to E<sub>2g</sub><sup>1</sup> and A<sub>1g</sub> mode. It is deemed that the E<sub>2g</sub><sup>1</sup> mode peak is related to the in-layer displacements of Mo and S atoms, whereas the A<sub>1g</sub> mode peak involves the out-of-layer symmetric displacements of S atoms along the *c*-axis.<sup>43,44</sup> It is noticed that the intensities of E<sub>2g</sub><sup>1</sup> and A<sub>1g</sub> peaks of the MoS<sub>2</sub> microspheres are lower than those of the MoS<sub>2</sub> nanosheets, suggesting some defect sites in the crystal structure of MoS<sub>2</sub>.<sup>45</sup>

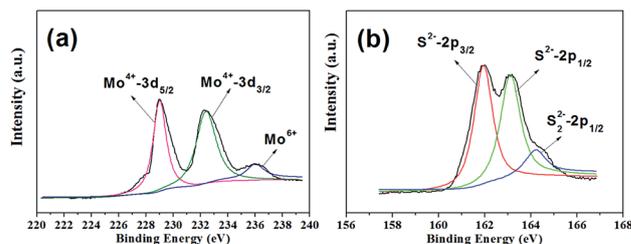


Fig. 3 High-resolution XPS spectra of the as-prepared MoS<sub>2</sub> microspheres. (a) Mo 3d; (b) S 2p.



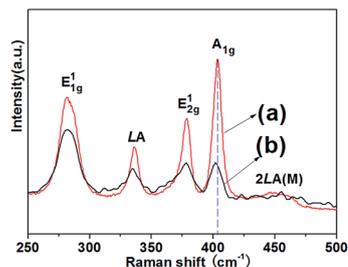


Fig. 4 Raman spectra of the as-prepared (a) MoS<sub>2</sub> nanosheets and (b) MoS<sub>2</sub> microspheres.

Besides, it can be discerned that the A<sub>1g</sub> peak of MoS<sub>2</sub> microspheres has a down shift in comparison with that of the MoS<sub>2</sub> nanosheets, which further confirms the decreased layers.<sup>46</sup> In addition, the appearance of E<sub>1g</sub><sup>1</sup>, LA as well as 2LA(M) peaks is associated with the vibration of one MoS<sub>2</sub> layer against neighboring layers and is called the rigid layer mode.<sup>43,44</sup>

The surface area of the as-prepared MoS<sub>2</sub> samples were determined by nitrogen adsorption–desorption isotherm measurements. A typical type IV can be observed in Fig. 5, indicating the presence of a mesoporous structure for both samples. The BET specific surface area of the MoS<sub>2</sub> microspheres was measured as about 28.39 m<sup>2</sup> g<sup>-1</sup>, which is larger than that of the MoS<sub>2</sub> nanosheets (14.06 m<sup>2</sup> g<sup>-1</sup>). The pore-size distribution plots of all samples were obtained from the adsorption branch of the N<sub>2</sub> adsorption–desorption isotherms by BJH method. It can be seen that the mesopores with a size of 3.4 nm are dominant in the MoS<sub>2</sub> nanosheets. By contrast, the presence of different pores (5.6 and 11.4 nm) for the MoS<sub>2</sub> microspheres can be observed with a broad pore-size distribution. Large surface area and porous feature are critical for affording more active sites for electrode reactions and promoting charge carriers transfer at the electrolyte/electrode interface, which results in observably enhanced electrochemical performances.

Time-dependent experiment was also carried out to investigate the formation process of the as-prepared MoS<sub>2</sub> hierarchical microspheres. It can be observed in Fig. 6a that spherical MoS<sub>2</sub>/ZnS composites with numerous tiny nanoparticles on the surface were formed at the initial hydrothermal stage. Fig. 6b and c display that with the hydrothermal reaction proceeding,

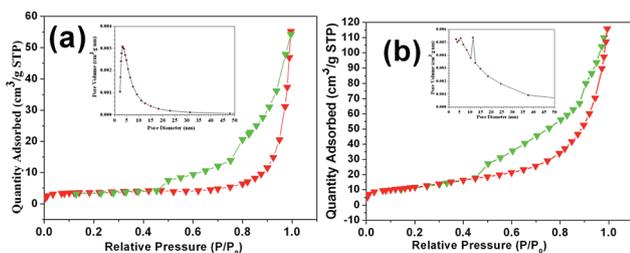


Fig. 5 Nitrogen adsorption–desorption isotherm of (a) MoS<sub>2</sub> nanosheets and (b) MoS<sub>2</sub> microspheres. The inserted figure is the pore-size distribution.

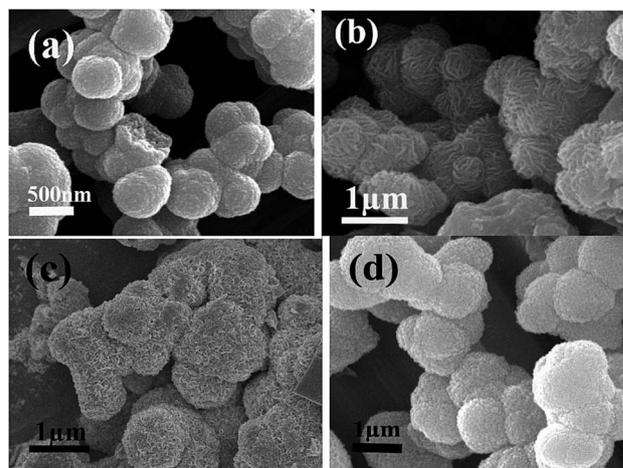


Fig. 6 SEM images of the MoS<sub>2</sub> samples prepared by zinc ion-assisted hydrothermal reaction at 240 °C for (a) 1 h, (b) 5 h, (c) 9 h, (d) SEM image of the ZnS samples prepared *via* a similar hydrothermal process at 240 °C for 24 h.

an increasing number of MoS<sub>2</sub> nanosheets appeared on the surfaces of the microspheres. For comparison, ZnS samples were also synthesized through a similar hydrothermal route as depicted in Fig. 6d, which manifested a sphere-like morphology.

Based on the above results, the formation of the hierarchical MoS<sub>2</sub> microspheres in our synthetic route can be illustrated in Fig. 7. Firstly, as MoO<sub>4</sub><sup>2-</sup> anions were introduced to the Zn<sup>2+</sup>-containing solution before hydrothermal treatment, no ZnMoO<sub>4</sub> precipitates appeared. The combination of Zn<sup>2+</sup>–MoO<sub>4</sub><sup>2-</sup> might be formed *via* strong electrostatic attraction. Secondly, during the following hydrothermal process, Zn<sup>2+</sup> and MoO<sub>4</sub><sup>2-</sup> ions reacted with H<sub>2</sub>S arising from the decomposition of thiocarbamide to produce small ZnS and MoS<sub>2</sub> nanoparticles, respectively. Due to the high surface energy, these nanoparticles were liable to aggregate together to form spherical composite particles. Owing to the anisotropic characteristic, the MoS<sub>2</sub> nanoparticles began to evolve into 2D nanosheets. These nanosheets gradually grew larger, interconnected together to form MoS<sub>2</sub> nanosheets/ZnS microspheres. With removal of ZnS by acid erosion, the MoS<sub>2</sub> microspheres could be obtained. The detailed formation mechanism needs to be further investigated.

### 3.2 Electrochemical performance of the sample electrodes

The pseudocapacitive properties of the MoS<sub>2</sub> sample electrodes was tested in a 3 M KOH aqueous electrolyte. The CV curves of

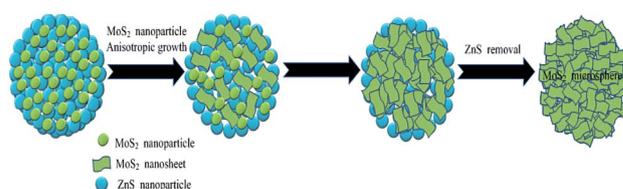


Fig. 7 Illustration of the formation process of the MoS<sub>2</sub> microspheres.



both MoS<sub>2</sub> electrodes were plotted in Fig. 8a for comparison. Evidently, the CV curves of two electrodes are different from the ideal rectangular curves originating from the electric double-layer capacitance, indicating a typical pseudocapacitive mechanism according to the redox peaks.<sup>2,3</sup> The prominent cathodic peaks situated at around 0.16–0.20 V can be attributed to the electrochemical insertion of K<sup>+</sup> ions into the MoS<sub>2</sub> interlayer. The corresponding anodic peaks located at about 0.27–0.32 V can be attributed to the extraction of K<sup>+</sup> ions from layered MoS<sub>2</sub>.<sup>15–19</sup> The nearly symmetrical redox peaks are indicative of high reversibility of the insertion/extraction process. As is well known, the specific capacitance is proportional to the area of the CV curves.<sup>2,3</sup> It is apparent that the MoS<sub>2</sub> microspheres possess a much larger CV curve area than that of MoS<sub>2</sub> nanosheets, demonstrating that the MoS<sub>2</sub> microspheres have a higher capacitance value. Moreover, it can be seen that the CV area of pure Ni foam is almost negligible compared with those of the MoS<sub>2</sub> electrodes, revealing the almost no capacitance contribution of the current collector. The CV curves under the different sweep rates are displayed in Fig. 8b and c, respectively. As the scan rate increases, CV curves of all the electrodes still retain a similar shape in spite of a small shift of peak positions owing to the polarization effect.<sup>47</sup> The area under the curve increased with increasing scan rate, meaning that the MoS<sub>2</sub> electrodes show the ideal supercapacitive behavior. The increase in current with increasing scan rate indicates that the kinetics of the interfacial faradic redox reactions and the rates of electronic and ionic transmission are rapid enough at scan rates as high as 100 mV s<sup>-1</sup>.<sup>48</sup> Fig. 8d shows the change in scan rate with respect to the specific capacitance. With the scan rate increasing from 5 mV s<sup>-1</sup> to 100 mV s<sup>-1</sup>, according to eqn (1), the specific capacitances of MoS<sub>2</sub> nanosheet and MoS<sub>2</sub> microsphere electrodes decrease from 211.3 to 85.1 F g<sup>-1</sup> and 294.4 to

209.2 F g<sup>-1</sup>, respectively. Obviously, MoS<sub>2</sub> microsphere electrode delivers a higher capacitance retention of 71% than that of MoS<sub>2</sub> nanosheet electrode (40%). The decrease in capacitance could be attributed to the presence of inner active sites, which cannot sustain the redox transitions completely at higher scan rates.<sup>48</sup>

Galvanostatic charge–discharge was carried out to measure the specific capacitance of electrochemical capacitors at constant current. Fig. 9a shows galvanostatic charge–discharge curves of the MoS<sub>2</sub> nanosheet and MoS<sub>2</sub> microsphere electrodes at a current density of 1 A g<sup>-1</sup>, respectively. Apparently, the latter manifests a longer discharging time than that of the former, representing a higher discharge capacitance, which is in agreement with CV results. Fig. 9b and c show charge–discharge curves of the two electrodes at various current densities. For the MoS<sub>2</sub> nanosheet electrode, according to eqn (2), the discharge specific capacitance values are calculated to be 217.3, 143.4, 124.3, 90.6 and 58.1 F g<sup>-1</sup> at 0.5, 1, 2, 4 and 10 A g<sup>-1</sup>, respectively. By contrast, the MoS<sub>2</sub> microsphere electrode delivers a much higher capacitance of 294.6, 254.0, 185.7, 157.8 and 134.1 F g<sup>-1</sup> at 0.5, 1, 2, 4 and 10 A g<sup>-1</sup>, respectively. The relationship between specific capacitance and current density is illustrated in Fig. 9d. MoS<sub>2</sub> microsphere exhibits a capacitance of 134.1 F g<sup>-1</sup> at 10 A g<sup>-1</sup> with a capacitance retention of 46% relative to 0.5 A g<sup>-1</sup>. In contrast, the MoS<sub>2</sub> nanosheet electrode delivers a much smaller capacitance value of 58.1 F g<sup>-1</sup> at 10 A g<sup>-1</sup> with only 27% retention compared with 0.5 A g<sup>-1</sup>. The greatly enhanced electrochemical performances of MoS<sub>2</sub> microsphere can be attributed to the robust 3D hierarchical architecture, which can be favorable to offering sufficient surface area for electrochemical reactions and promoting charge carriers transfer at the electrolyte/electrode interface.

Furthermore, the good electrochemical properties of the MoS<sub>2</sub> microsphere electrode were further confirmed by the

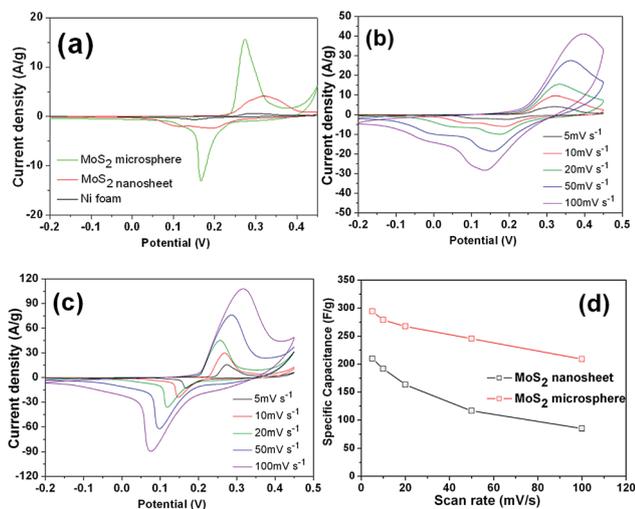


Fig. 8 Electrochemical measurements of MoS<sub>2</sub> nanosheet and MoS<sub>2</sub> microsphere electrodes: (a) cyclic voltammograms (CV) within the optimized potential range of –0.2 to 0.45 V in 3 M KOH solution at a scan rate of 5 mV s<sup>-1</sup>, voltammetric responses of (b) MoS<sub>2</sub> nanosheet and (c) MoS<sub>2</sub> microsphere electrodes at various scan rates, (d) specific capacitance obtained at different scan rates.

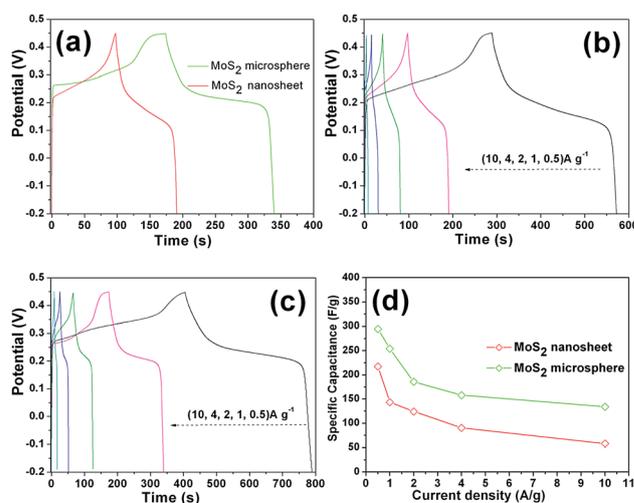


Fig. 9 (a) Galvanostatic charge–discharge curves of the MoS<sub>2</sub> sample electrodes at 1 A g<sup>-1</sup>; galvanostatic charge–discharge curves of (b) the MoS<sub>2</sub> nanosheet electrode and (c) the MoS<sub>2</sub> microsphere electrode at different current densities; (d) specific discharge capacitances vs. current densities of the two sample electrodes.



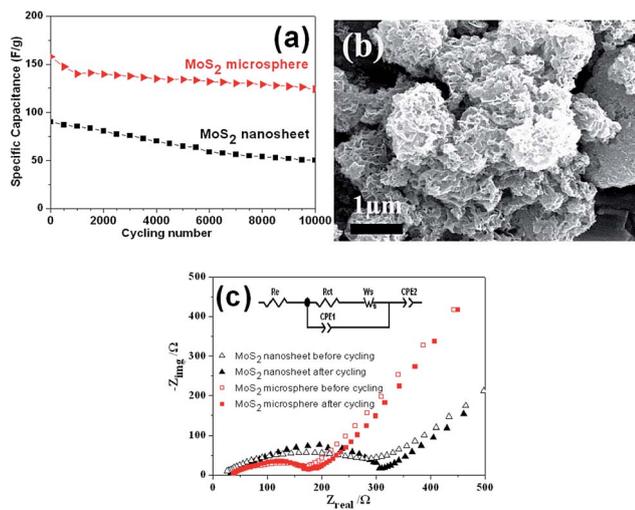


Fig. 10 (a) Cycling performance of the as-prepared MoS<sub>2</sub> sample electrodes at 4 A g<sup>-1</sup>, (b) SEM image of the MoS<sub>2</sub> microspheres after cycling and (c) EIS spectra of the sample electrodes before and after cycling, inset is the equivalent circuit.

long-term cycling test. As shown in Fig. 10a, during 10 000 cycles testing, the MoS<sub>2</sub> nanosheet electrode exhibits an obvious capacitance loss up to 44.3%. The obvious decay in capacitance may be caused by chemical dissolution and ion intercalation/deintercalation induced volume change of active materials. For MoS<sub>2</sub> microsphere electrode, still 78.5% of the initial capacitance can be maintained after long-term cycles. The capacitive decay observed for MoS<sub>2</sub> microsphere electrode during the process of the charge–discharge cycling can be attributed to the partial collapse of the MoS<sub>2</sub> microsphere as shown in Fig. 10b. In comparison with MoS<sub>2</sub> nanosheets, the prominently enhanced electrochemical performances of MoS<sub>2</sub> microspheres can be attributed to the 3D hierarchical architecture, which can be favorable to maintaining structural integrity, offering sufficient surface area for electrochemical reactions and promoting charge carriers transfer at the electrolyte/electrode interface.

EIS measurements were performed to understand why MoS<sub>2</sub> microsphere electrode exhibits a superior electrochemical performance. Fig. 10c displays that both impedance spectra are composed of semicircles in the high frequency region followed by a linear slope in the low frequency region. The diameter of the characteristic depressed semicircle in the high frequency regions is related to charge transfer resistance. A linear region in the low-frequency range corresponds to the diffusive resistance (Warburg impedance). The steeper straight line of MoS<sub>2</sub> microsphere reveals a faster ion diffusion in comparison with MoS<sub>2</sub> nanosheet. The equivalent circuit (inset of Fig. 10c) for fitting the EIS data contains the internal resistance ( $R_e$ ), the charge transfer resistance ( $R_{ct}$ ), the constant phase element (CPE<sub>1</sub>, CPE<sub>2</sub>) involving the double layer capacitance and the limit capacitance, and Warburg impedance ( $W_s$ ).<sup>21,49</sup> The  $R_e$  represents a combined resistance of ionic resistance of electrolyte, intrinsic resistance of substrate, and contact resistance at the active material/current collector interface. The  $R_{ct}$  is

Table 1  $R_{ct}$  values of the MoS<sub>2</sub> nanosheet and MoS<sub>2</sub> microsphere electrodes before and after cycling

Sample electrode	$R_{ct}/\Omega$	
	Before cycling	After cycling
MoS <sub>2</sub> nanosheet	282.3	298.4
MoS <sub>2</sub> microsphere	139.8	147.5

caused by faradaic redox process. The  $W_s$  is a result of the frequency dependence of ion diffusion/transport in the electrolyte to the electrode surface. The smaller diameter of the Nyquist circle of MoS<sub>2</sub> microsphere means a fast electron transfer process at the electrode/electrolyte interface.<sup>50</sup> In addition, it is noted that the diameter of the Nyquist circle after cycling became slightly larger, indicating an increase of  $R_{ct}$ , which is probably due to the loss of adhesion of some active material with the current collector during the charge/discharge cycling.<sup>49,51</sup> The  $R_{ct}$  values obtained by data fitting according to the equivalent circuit model are summarized in Table 1.

## 4. Conclusions

In conclusion, hierarchical MoS<sub>2</sub> microspheres composed of few-layered nanosheets have been successfully synthesized *via* a facile zinc ion-assisted hydrothermal route combined with an acid erosion method. It is found that the initially generated MoS<sub>2</sub>/ZnS composites acted as a precursor for the formation of the hierarchical MoS<sub>2</sub> microspheres. Furthermore, the hierarchical MoS<sub>2</sub> microspheres deliver a high specific capacitance as well as good rate and cycle ability for supercapacitor.

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